

Description

- High speed switching application.
- Analog switch application.

Features

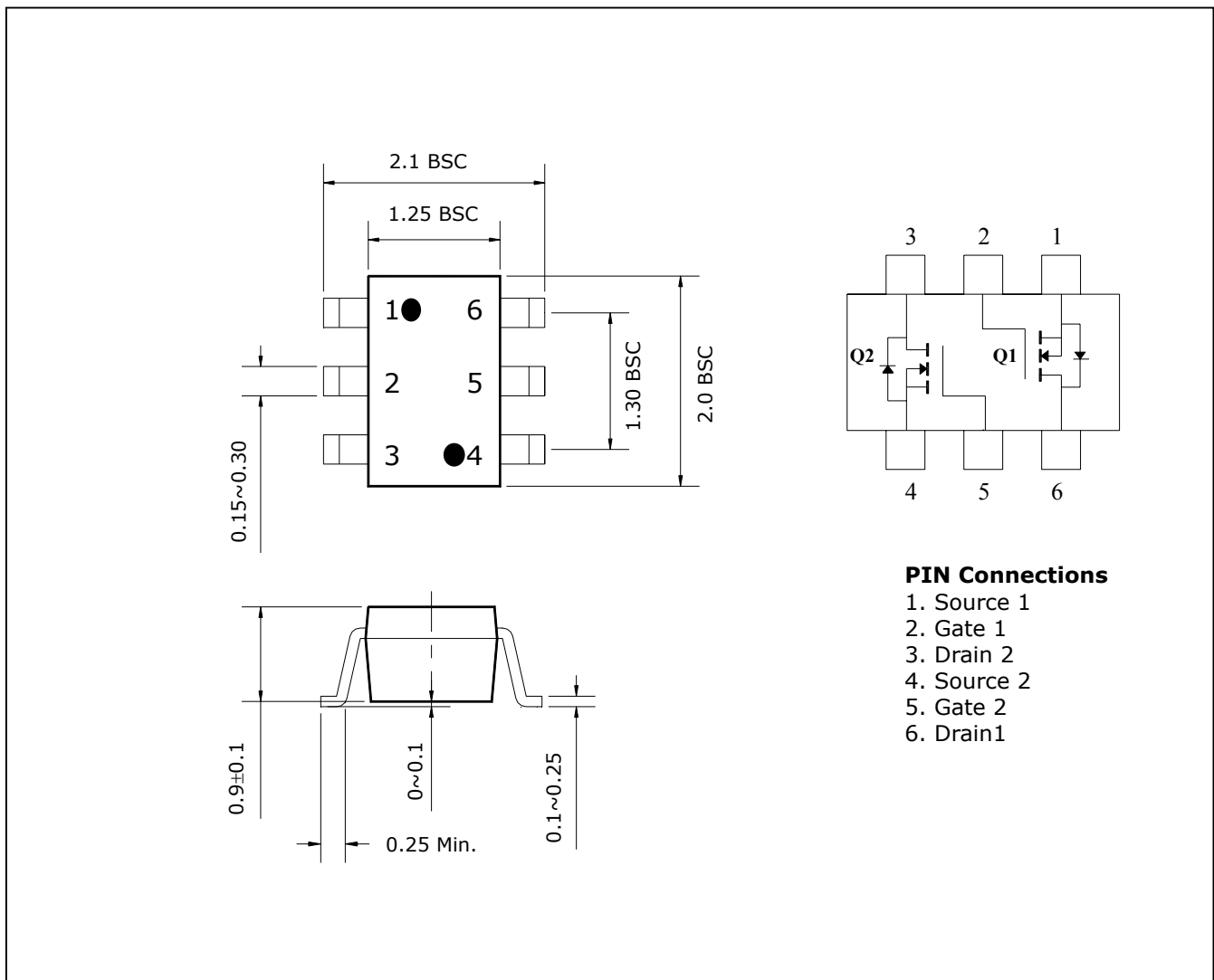
- 2.5V Gate drive.
- Low threshold voltage : $V_{th} = 0.5 \sim 1.5V$.
- Two STK1828 Chips in SOT-363 Package.

Ordering Information

Type NO.	Marking	Package Code
SUF520J	H	SOT-363

Outline Dimensions

unit : mm



Absolute maximum ratings (Q1, Q2 Common)

(Ta=25°C)

Characteristic	Symbol	Ratings	Unit
Drain-Source voltage	V_{DS}	20	V
Gate-Source voltage	V_{GSS}	10	V
DC Drain current	I_D	50	mA
Power dissipation	P_D^*	200	mW
Channel temperature	T_{ch}	150	°C
Storage temperature range	T_{stg}	-55~150	°C

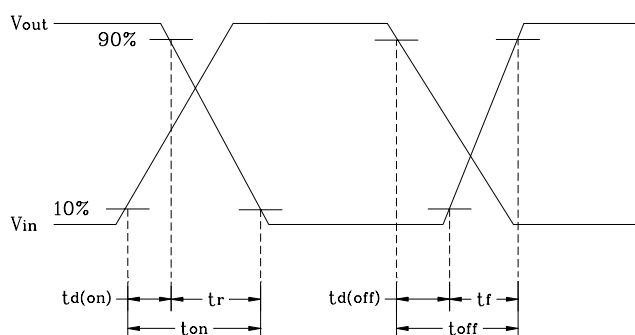
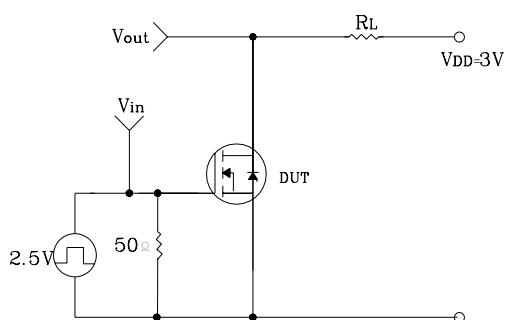
* : Total rating

Electrical Characteristics

(Ta=25°C)

Characteristic	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Drain-Source breakdown voltage	BV_{DSS}	$I_D=100\mu A, V_{GS}=0$	20			V
Gate-Threshold voltage	V_{th}	$I_D=0.1mA, V_{DS}=3V$	0.5		1.5	V
Drain cut-off current	I_{DSS}	$V_{DS}=20V, V_{GS}=0$			1	μA
Gate leakage current	I_{GSS}	$V_{GS}=10V, V_{DS}=0$			1	μA
Drain-Source on-resistance	$R_{DS(ON)}$	$V_{GS}=2.5V, I_D=10mA$		20	40	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS}=3V, I_D=10mA$	20			mS
Input capacitance	C_{iss}	$V_{DS}=3V, V_{GS}=0, f=1MHz$		5.5		pF
Output capacitance	C_{oss}	$V_{DS}=3V, V_{GS}=0, f=1MHz$		6.5		pF
Reverse Transfer capacitance	C_{rss}	$V_{DS}=3V, V_{GS}=0, f=1MHz$		1.6		pF
Turn-on time	t_{ON}	$V_{DD}=3V, I_D=10mA$ $V_{GEN}=0\sim 2.5V$		0.14		μs
Turn-off time	t_{OFF}	$V_{DD}=3V, I_D=10mA$ $V_{GEN}=0\sim 2.5V$		0.14		μs

* Switching Time Test Circuit



Electrical Characteristic Curves

Fig.1 $I_D - V_{DS}$

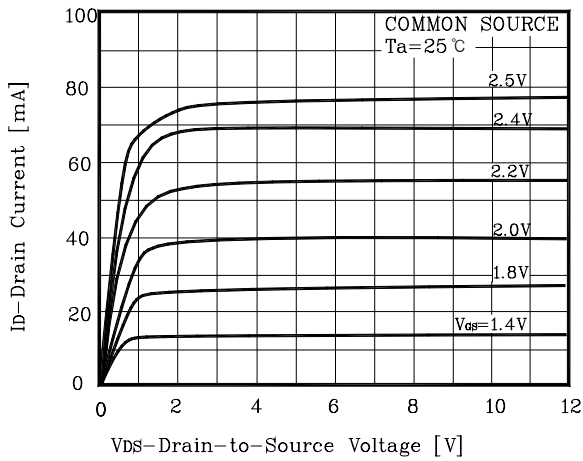


Fig.2 $P_D^* - T_a$

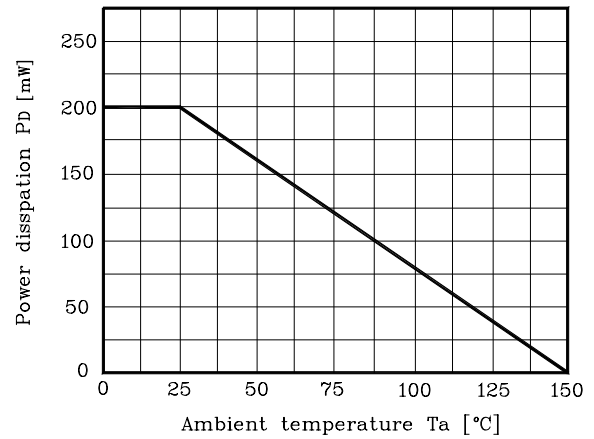


Fig.3 $I_{DR} - V_{DS}$

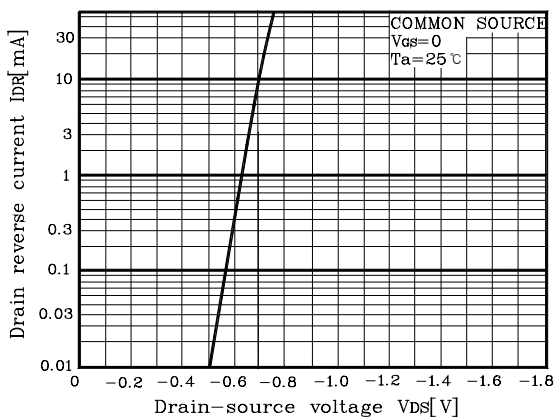


Fig.4 $I_D - V_{GS}$

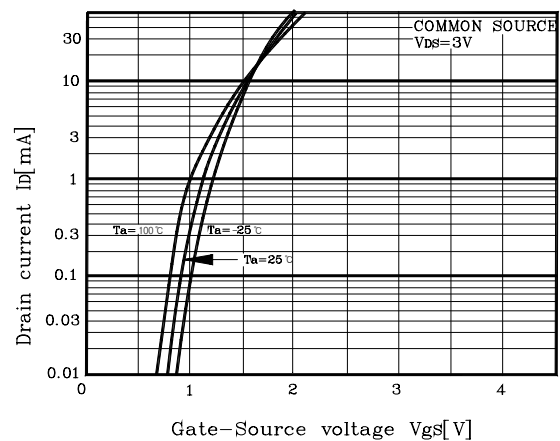


Fig.5 $|Y_{fs}| - I_D$

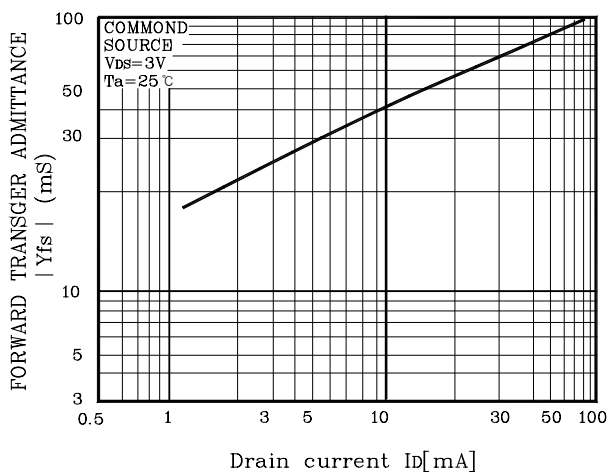
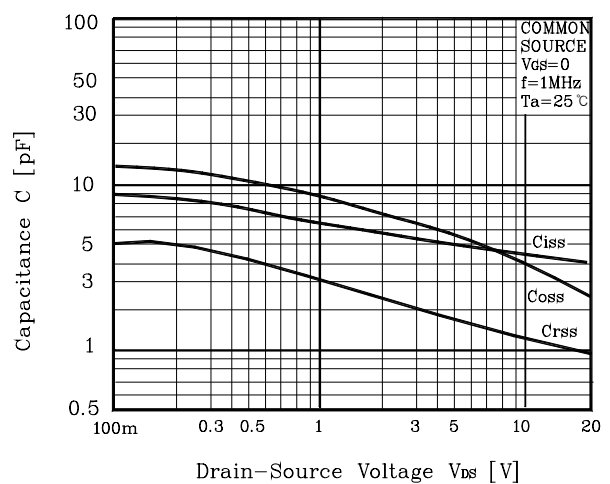


Fig.6 C - VDS



Electrical Characteristic Curves

Fig.7 V_{DS} - I_D

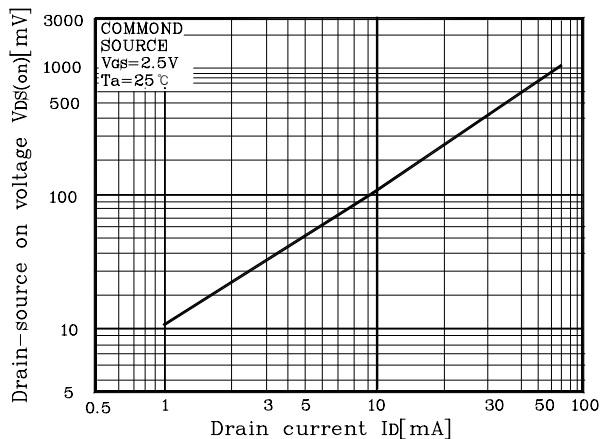


Fig.8 t - I_D

